



Physikalisches Institut Kepler Center for Astro and Particle Physics





Dead layer and active volume determination of enriched BEGe detectors for the GERDA experiment

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- Located at the Laboratori Nationali del Gran Sasso (LNGS), Italy, with a natural shielding from cosmic radiation of ~ 3800 m water equivalent.
- Uses Ge diodes enriched in ⁷⁶Ge as source and detector





- Liquid Argon (LAr) is used as γ -shield and cooling medium
- The Germanium detectors are operated "naked" in LAr





Phase I

Between 11/2011 and 05/13 with ~ 18 kg of ^{enr}Ge diodes (mostly coax type)



Phase II

- ~ 20 kg of BEGe detectors enriched in ⁷⁶Ge at 86 % level will be additionally deployed
- 5 BEGe's with a total mass of ~ 3 kg already deployed in GERDA since July 2012
- Physics goal of Phase II is to increase our sensitivity and especially the reduction of the background index in the ROI (Q_{ββ} = 2039 keV) to a level of 10⁻³ cts/(keV · kg · yr)





- Smaller size compared to the Phase I coax. detectors
- Smaller size of read-out-electrode
 - Lower capacitance
 - Lower noise
 - Better energy resolution
 - (~ 1.75 keV @ 1.33 MeV)
- Enhanced pulse shape discrimination performance due to peculiar electric field created by the small contact

→ Allows in particular to discriminate
 single-site events (0vββ-decay-like) from
 multi-site events (gamma-ray background events)







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Acceptance tests of enriched BEGe detectors

- Determine all the important **detector parameters** of our 30 BEGe detectors, like depletion voltage, **detector active volume**, dead layer uniformity over the surface, charge collection uniformity and test the performance of the diodes in terms of energy resolution and quality of pulse shape discrimination
- Do the detectors fulfill our requirements and the specs of the manufacturer?
- **Complete characterization** of the detector properties prior to their installation in the GERDA experiment

HADES - High Activity Disposal Experimental Site

- Location for **acceptance testing** and **storage** of the diodes
- Located in at the Belgian Nuclear Research Center SCK • CEN, Mol, Belgium



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- The goals of GERDA
 - Determination of the **0vbb half life** or improved lower limit with high precision
 - Measure the half life of 2vbb with high precision
- The Active Volumes of the detectors and therefore the Active Masses affect the value for the half life and the **uncertainties** contribute to the **systematic errors**



Precise knowledge of Active Volumes is very important for the GERDA physics analysis

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How to measure the Active Volume?



- Li-diffused n+ contact.
- No depletion in this outer layer.
 - \rightarrow Dead layer in the range of 0.5 1.0 mm
- The Boron implanted contact is negligible,
 - **~** 0.6 μm
- Dead layer defines AV of the detector
- How can the DL thickness be measured?
 - DL cannot be measured from the Li diffusion process.
 - The Idea: Compare experimental γ-spectrum with MC spectra obtained with different DL thicknesses
 - MC spectrum which fits best to the experimental spectrum defines the DL
 - Possible observables: peak counts, ratios of peak counts, the full spectrum, ...









• Save hit positions and energies for every event



Spectra corresponding to different DL thicknesses



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- Save hit positions and energies for every event
- Reconstruct the energy and generate the MC spectra for different DL thicknesses by volume cuts in the postprocessing step



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cnt/0.1keV DL thickness 0.00 mm DL thickness 0.25 mm DL thickness 0.50 mm DL thickness 1.50 mm 10^{3} 10^{2} 10 ⁶⁰Co spectrum . 1173 keV peal 200 400 600 1000 1200 1400 800 Energy [keV] cnt/0.1keV 10₂ DL thickness 0.00 mm thickness 0.25 mm L thickness 0.50 mm OL thickness 1.50 mm 10 10^{3} 10^{2} 10 10^{-1} Am spectrum 10^{-2}

Spectra corresponding to different DL thicknesses

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60

80

100 Energy [keV]

40

 10^{-3}

20







- Save hit positions and energies for every event
- Reconstruct the energy and generate the MC spectra for different DL thicknesses by volume cuts in the postprocessing step
 - → Cut hits in the DL



cnt/0.1keV DL thickness 0.00 mm DL thickness 0.25 mm DL thickness 0.50 mm DL thickness 1.50 mm 10^{3} 10^{2} 10 ⁶⁰Co spectrum 1173 keV peak 200 400 1200 600 800 1000 1400 Energy [keV] Cut/0.1keV 10² DL thickness 0.00 mm thickness 0 25 mm L thickness 0.50 mm OL thickness 1.50 mm 10° 10^{3} 10^{2} 10 10^{-1} ²⁴¹Am spectrum 10^{-2} 10^{-3} 20 40 60 80 100

Spectra corresponding to different DL thicknesses

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Energy [keV]







- Save hit positions and energies for every event
- Reconstruct the energy and generate the MC spectra for different DL thicknesses by volume cuts in the postprocessing step
 → Cut hits in the DL
- 150 DL variations from 0 1.5 mm

Distance to side surface perturbation of the surface perturbation of the surface p-type Germanium

cnt/0.1keV DL thickness 0.00 mm DL thickness 0.25 mm DL thickness 0.50 mm DL thickness 1.50 mm 10^{3} 10^{2} 10 ⁶⁰Co spectrum 1173 keV peak 200 400 1200 600 800 10001400 Energy [keV] Cut/0.1keV 10² OL thickness 0.00 mm thickness 0 25 mm thickness 0.50 mm L thickness 1.50 mm 10 10^{3} 10^{2} 10 1 10^{-1} ²⁴¹Am spectrum 10^{-2} 10^{-3} 20 40 60 80 100

Spectra corresponding to different DL thicknesses

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Energy [keV]





- Use the two energetic γ -lines of ⁶⁰Co (1173 keV and 1333 keV)
- DL determined by comparing the experimental peak count rate with the MC simulation
- The intersection between MC rate as function of the DL and the measured rate defines the DL of the detector
- Calculate AV by geometrical function, assuming a homogeneous DL



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Avg. upper surface dead layer determination using ²⁴¹Am





- Simulate three $\gamma\text{-lines}$ of ^{241}Am
- Calculate the Ratio:

 $\frac{Counts(59.5 \, keV)}{Counts(99 \, keV) + Counts(103 \, keV)}$

- DL determined by comparing the experimental ratio of the γ-lines with the corresponding MC ratio
- The intersection between MC ratio as a function of the DL and the experimental ratio defines the average upper surface DL of the detector

 → Calculate AV by geometrical function, assuming a homogeneous DL thickness







Lead and copper shielding



Avg. upper surface dead layer determination using ²⁴¹Am

- Simulate three $\gamma\text{-lines}$ of ^{241}Am
- Calculate the Ratio:

 $\frac{Counts(59.5 \, keV)}{Counts(99 \, keV) + Counts(103 \, keV)}$

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- The intersection between MC ratio as a function of the DL and the experimental ratio defines the average upper surface DL of the detector

 → Calculate AV by geometrical function, assuming a homogeneous DL thickness



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Comparison of peak-counts (bulk) and ratio method (upper surface)



Ratio method with ²⁴¹Am

- ²⁴¹Am γ 's only penetrate upper surface
 - → Only upper surface (top DL) is probed
 - → Gives upper surface DL



Peak-Counts method with ⁶⁰Co

- ⁶⁰Co is sensitive to the whole detector volume
 - \rightarrow y's also penetrate into bulk
 - \rightarrow Probes also side and bottom DL



DL/AV values are only correct if the assumption of a homogeneous DL thickness is correct



Comparison of peak-counts (bulk) and ratio method (upper surface)



Ratio method with ²⁴¹Am

- $^{\rm 241}Am~\gamma 's$ only penetrate upper surface
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Energy Distribution @59.5409keV Babel Am241_59keV

-4 -3 -2 -1 0 1 2 3 4

400 300

200

100

x[cm]



Peak-Counts method with ⁶⁰Co

- ⁶⁰Co is sensitive to the whole detector volume
 - \rightarrow y's also penetrate into bulk
 - \rightarrow Probes also side and bottom DL



Energy Distribution @1173.0000keV Babel Co60



DL/AV values are only correct if the assumption of a homogeneous DL thickness is correct











	Systematic uncertainty	⁶⁰ Co Peak counts	
MC	MC statistics	~ 0.1 %	
	Geant4 physics processes	4.00 %	
	Gamma line probabilities	0.03 % (0.0006 %)	
Source	Source geometry (thickness)	0.02 %	
	Source material	0.01 %	Total syst. uncertainty propagated to DL : ~ 30 %
	Source distance	1.20 %	
	Source activity	1.00 %	
Detector	Diode dimensions	2.50 %	
Cryostat	Diode distance to endcap	1.00 %	Propagated to AV:
	Cryostat endcap thickness	0.15 %	~ 3.5%
	Cryostat detector cup thickness	0.06 %	
DAQ	Cryostat detector cup mat	0.03 %	
	Shaping time	0.2 %	
	DAQ dead time	5/10 % on deadtime	
Statistics	Stat. uncert. from measurement	Typically ~ 0.5-1.0 %	











	Systematic uncertainty	²⁴¹ Am Peak ratio
	MC statistics	~1%
MC	Geant4 physics processes	2.00 %
	Gamma line probabilities	~ 1.5 %
	Source geometry (thickness)	~ 0.02 %
Source	Source material	0.014 %
	Cryostat endcap thickness	0.31 %
Cryostat	Cryostat detector cup thickness	0.03 %
	Cryostat detector cup mat	0.01 %
Statistics	Stat. uncert. from measurement	Typically 0.8-4.0 %
	Total svst. unce	rtaintv

propagated to **DL**: ~ 6% Propagated to AV: ~ 0.5%





- Active volumes of the BEGe detectors are an important parameter for the GERDA Phase II physics analysis
- AV is determined via the DL with different methods (⁶⁰Co, ²⁴¹Am) by comparing experimental and MC spectra.
- Systematic uncertainties on the AV fraction are around \pm 0.5 % for the ²⁴¹Am method and around \pm 3.5 % for the ⁶⁰Co method
- Typical DL's of our detectors are between 0.5 and 1.0 mm
 → Around 89-94 % AV fractions
- Discrepancies between surface and bulk methods for many detectors observed

 → AV values obtained with ⁶⁰Co-method are systematically lower by (1-3 %)
 compared to the ²⁴¹Am surface probe result